# MOSFET – Power, Dual, N-Channel, for 1-Cell Lithium-ion Battery Protection

12 V, 2.75 mΩ, 33 A

# **EFC2K102ANUZ**

### Overview

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-cell lithium-ion battery applications.

### **Features**

- 2.5 V Drive
- Common–Drain type
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance

### **Applications**

• 1-Cell Lithium-ion Battery Charging and Discharging Switch

### **Specifications**

### **ABSOLUTE MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Parameter	Symbol	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>	12	V
Gate to Source Voltage	V <sub>GSS</sub>	±8	V
Source Current (DC)	IS	33	Α
Source Current (Pulse) PW ≤ 10 μs, duty cycle ≤ 1%	I <sub>SP</sub>	135	Α
Total Dissipation (Note 1)	P <sub>T</sub>	3.1	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{\theta JA}$	40.3	°C/W

<sup>1.</sup> Surface mounted on ceramic substrate (5000  $\text{mm}^2\times\text{0.8 mm}).$ 

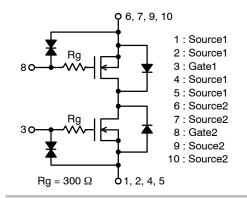


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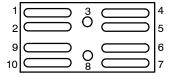
### www.onsemi.com

V <sub>SSS</sub>	R <sub>SS(on)</sub> Max	I <sub>S Max</sub>
12 V	2.75 m $\Omega$ @ 4.5 V	33 A
	2.85 mΩ @ 3.8 V	
	3.95 mΩ @ 3.1 V	
	6.1 mΩ @ 2.5 V	

# ELECTRICAL CONNECTION N-Channel



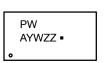
### **PIN ASSIGNMENT**



### **MARKING DIAGRAM**



WLCSP10 2.98x1.49x0.1 CASE 567ZG



PW = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Assembly Lot
■ = Pb-Free Package

### ORDERING INFORMATION

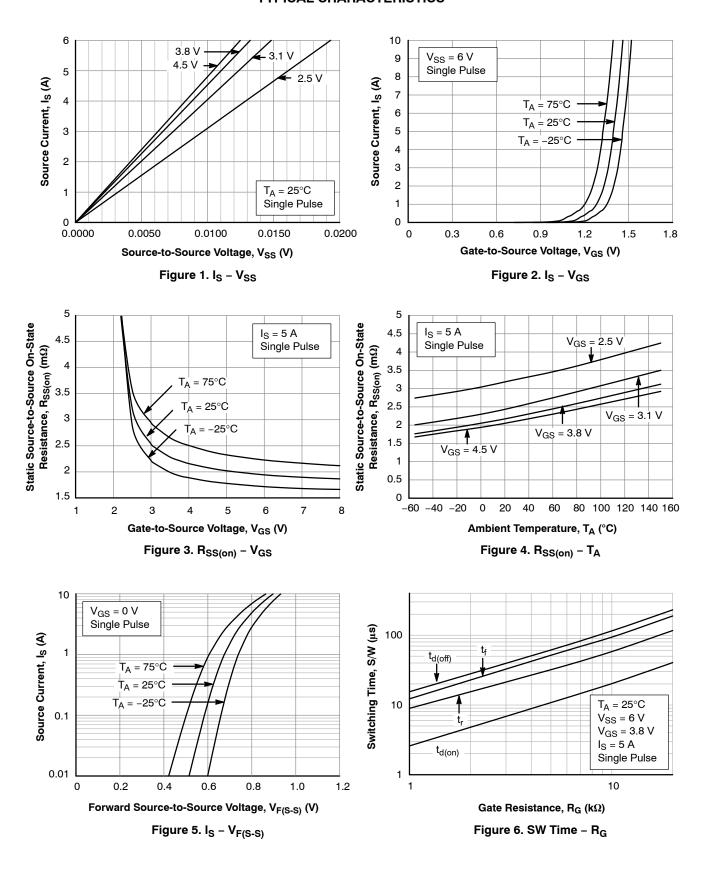
See detailed ordering and shipping information on page 6 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C)

				Value			
Parameter	Symbol	Conditions	s	Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I <sub>S</sub> = 1 mA, V <sub>GS</sub> = 0 V	Test Circuit 1	12	-	-	V
Zero-Gate Voltage Source Current	I <sub>SSS</sub>	V <sub>SS</sub> = 10 V, V <sub>GS</sub> = 0 V	Test Circuit 1	-	-	1	μΑ
Gate to Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 8 \text{ V}, V_{SS} = 0 \text{ V}$	Test Circuit 2	-	-	±1	μΑ
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>SS</sub> = 6 V, I <sub>S</sub> = 1 mA	Test Circuit 3	0.4	-	1.3	V
Static Source to Source On-State	R <sub>SS(on)</sub>	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 4.5 V	Test Circuit 4	1.55	2.10	2.75	mΩ
Resistance		I <sub>S</sub> = 5 A, V <sub>GS</sub> = 3.8 V	Test Circuit 4	1.60	2.20	2.85	mΩ
		I <sub>S</sub> = 5 A, V <sub>GS</sub> = 3.1 V	Test Circuit 4	1.65	2.40	3.95	mΩ
		I <sub>S</sub> = 5 A, V <sub>GS</sub> = 2.5 V	Test Circuit 4	1.90	3.10	6.10	mΩ
Turn-ON Delay Time	t <sub>d(on)</sub>	$V_{SS}$ = 6 V, $V_{GS}$ = 3.8 V, $I_{S}$ = 5 A, $R_{g}$ = 10 kΩ Test Circuit 5		-	20	-	μs
Rise Time	t <sub>r</sub>			-	58	-	μs
Turn-OFF Delay Time	t <sub>d(off)</sub>			-	115	-	μs
Fall Time	t <sub>f</sub>			-	94	_	μs
Total Gate Charge	Qg	V <sub>SS</sub> = 6 V,V <sub>GS</sub> = 3.8 V, I <sub>S</sub> = 5 A		-	42	_	nC
Forward Source to Source Voltage	$V_{F(S-S)}$	I <sub>S</sub> = 3 A, V <sub>GS</sub> = 0 V Test Circuit 7		-	0.75	1.20	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **TYPICAL CHARACTERISTICS**



## TYPICAL CHARACTERISTICS (Continued)

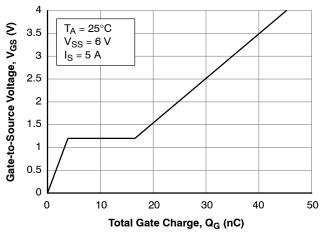


Figure 7. V<sub>GS</sub> - Q<sub>G</sub>

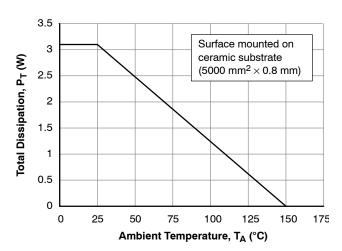


Figure 8. P<sub>T</sub> – T<sub>A</sub>

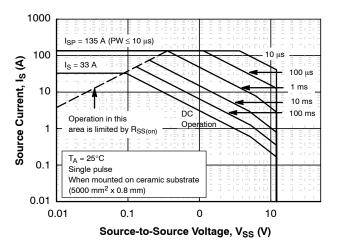


Figure 9. Safe Operating Area

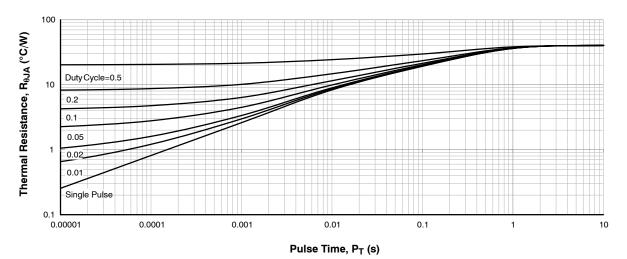
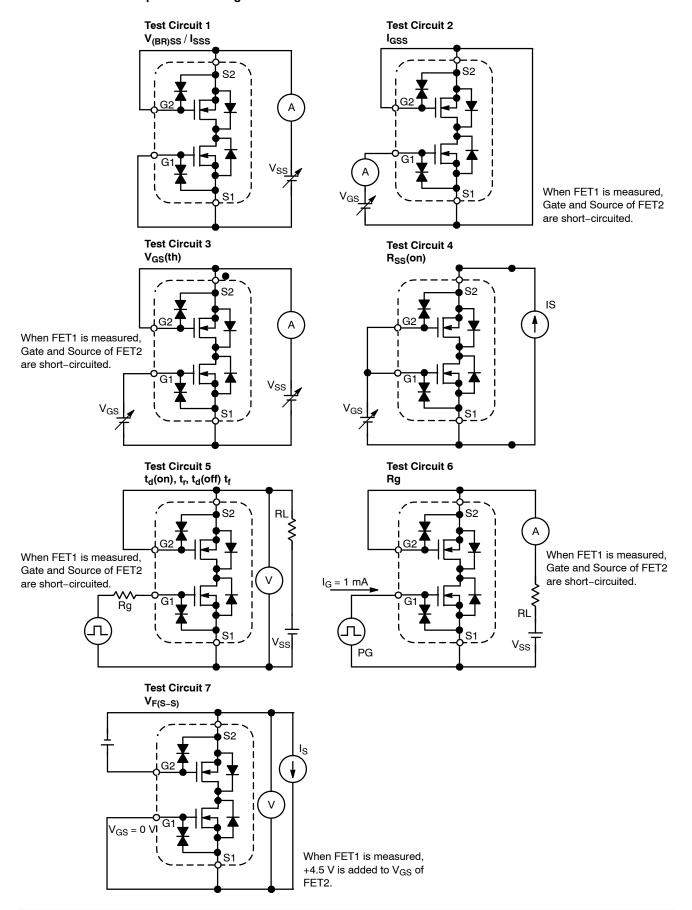


Figure 10. Thermal Response

### Test Circuits are Example of Measuring FET1 Side



### **ORDERING INFORMATION**

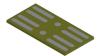
Device	Marking	Package	Shipping (Qty / Packing) <sup>†</sup>
EFC2K102ANUZTDG	PW	WLCSP10, 2.98x1.49x0.1 (Pb-Free/Halogen Free)	5,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: Since the EFC2K102ANUZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects. Please contact sales for use except the designated application.







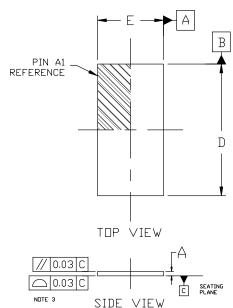
### WLCSP10 2.98x1.49x0.1 CASE 567ZG **ISSUE O**

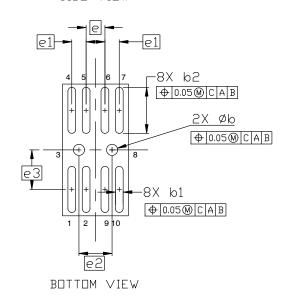
**DATE 27 MAY 2020** 

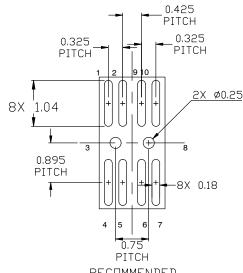
### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009
- CONTROLLING DIMENSION: MILLIMETERS
- COPLANARITY APPLIES TO ALL PADS

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.07	0.10	0.13	
b	0.22	0.25	0.28	
b1	0.145	0.175	0.205	
b2	1.01	1.04	1.07	
D	2.95	2.98	3.01	
E	1.46	1.49	1.52	
е	0.425 BSC			
e1	0.325 BSC			
e2	0.75 BSC			
e3	0.895 BSC			







### RECOMMENDED MOUNTING FOOTPRINT

- For additional information on our Pb-Free strategy and soldering details, please download the IN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.
  - \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

### **GENERIC MARKING DIAGRAM\***

XXXXX. AYWZZ=

XXXX = Specific Device Code

= Assembly Location Α

= Year

W = Work Week

= Assembly Lot Code ZZ

= Pb-Free Package

(Note: Microdot may be in either location)

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